



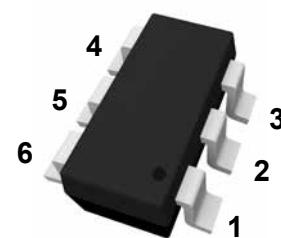
Features

- Fast Switching
- Low Gate Charge and $R_{DS(on)}$
- High power and current handing capability

Applications

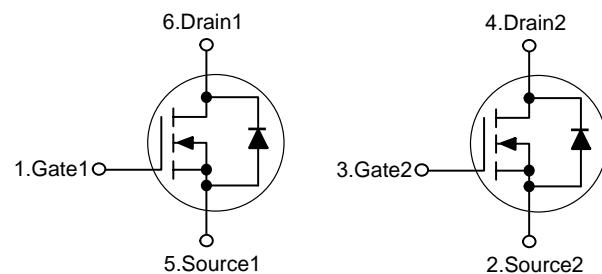
- Battery protection
- Load switch
- Power management

SOT-23-6



Marking Code: DS02

Schematic Diagram



Absolute Maximum Ratings

Ratings at $T_A = 25^\circ\text{C}$ unless otherwise specified.

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	V
Drain Current-Continuous	I_D	2	A
Drain Current-Plused ^{Note1}	I_{DM}	10	A
Maximum Power Dissipation	P_D	1	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	$^\circ\text{C}$

Thermal Characteristics

Parameter	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Ambient ^{Note2}	$R_{\theta JA}$	125	$^\circ\text{C/W}$



PJM4602DNG-S

Dual N-Channel MOSFET

Electrical Characteristics

T_A=25°C unless otherwise specified.

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V I _D =250μA	20	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±12V, V _{DS} =0V	-	-	±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	0.4	0.8	1.2	V
Drain-Source On-State Resistance ^{Note3}	R _{DS(ON)}	V _{GS} =2.5V, I _D =1A	-	60	80	mΩ
		V _{GS} =4.5V, I _D =2A	-	48	60	mΩ
Forward Transconductance ^{Note3}	g _{FS}	V _{DS} =5V, I _D =2A	-	5	-	S
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =10V, V _{GS} =0V, f=1.0MHz	-	260	-	pF
Output Capacitance	C _{oss}		-	48	-	pF
Reverse Transfer Capacitance	C _{rss}		-	27	-	pF
Switching Characteristics						
Turn-on Delay Time	t _{d(on)}	V _{DD} =10V, R _L =3.3Ω V _{GS} =4.5V, R _{GEN} =6Ω	-	2.5	-	nS
Turn-on Rise Time	t _r		-	3.2	-	nS
Turn-Off Delay Time	t _{d(off)}		-	21	-	nS
Turn-Off Fall Time	t _f		-	3	-	nS
Total Gate Charge	Q _g	V _{DS} =10V, I _D =2A, V _{GS} =4.5V	-	2.9	5	nC
Gate-Source Charge	Q _{gs}		-	0.4	-	nC
Gate-Drain Charge	Q _{gd}		-	0.6	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage ^{Note 3}	V _{SD}	V _{GS} =0V, I _s =2A	-	-	1.2	V
Diode Forward Current ^{Note 2}	I _s		-	-	2	A

Notes: 1. Repetitive rating: pulsed width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t ≤ 10 sec.

3. Pulse width ≤ 300μs, duty cycle ≤ 2%



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Electrical Characteristics Curves

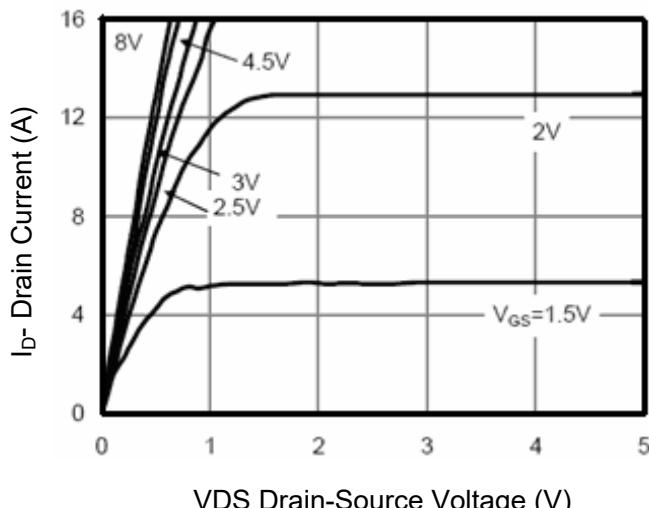


Figure 1 Output Characteristics

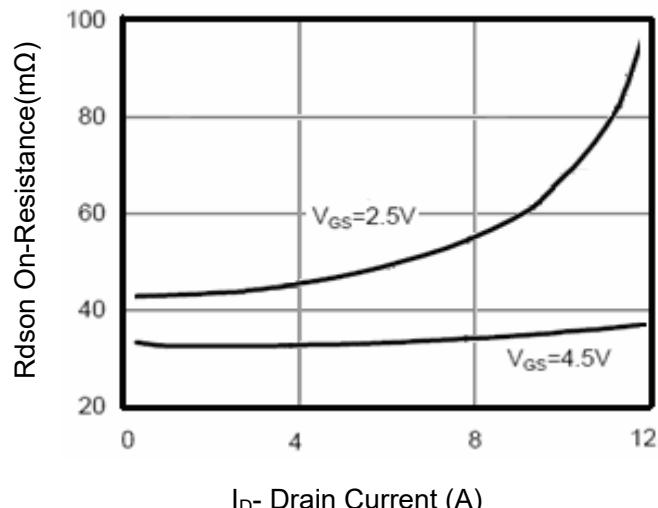


Figure 2 Drain-Source On-Resistance

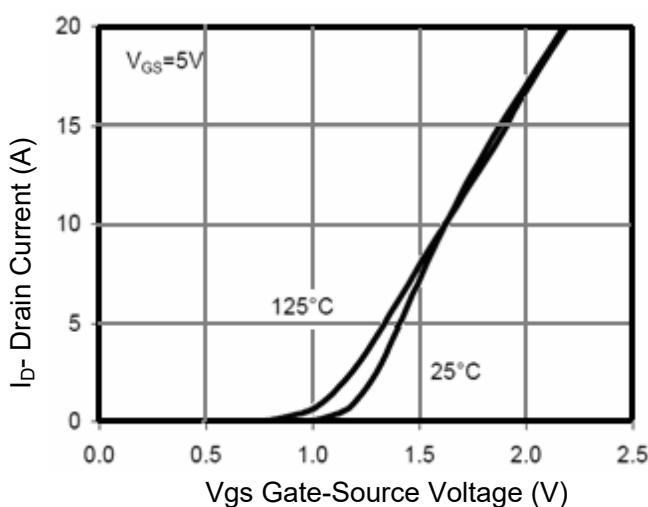


Figure 3 Transfer Characteristics

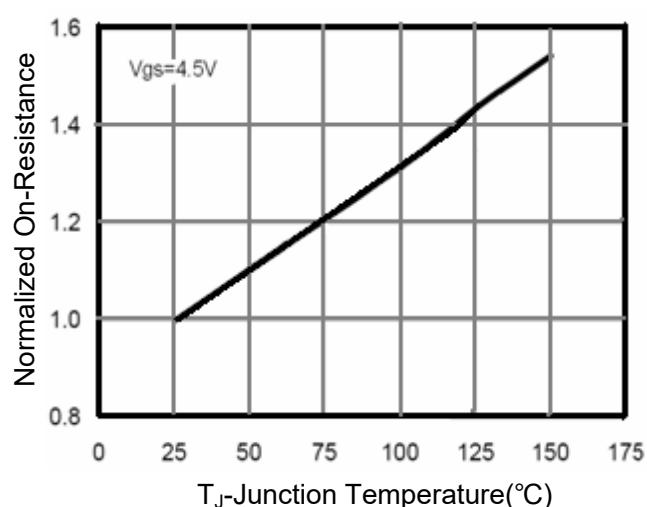


Figure 4 Drain-Source On-Resistance

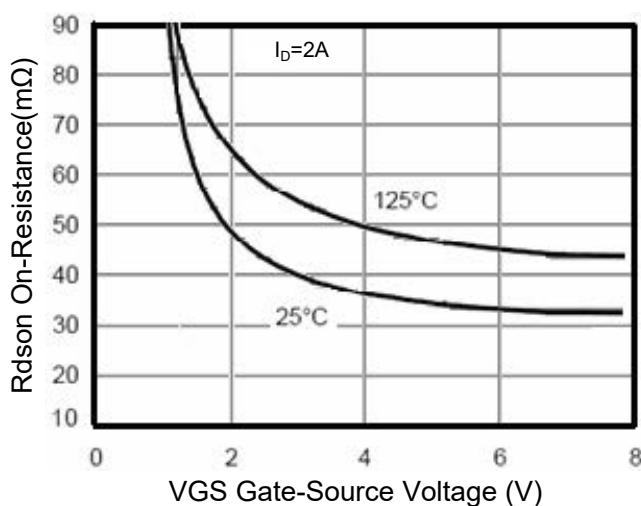


Figure 5 $R_{DS(on)}$ vs V_{GS}

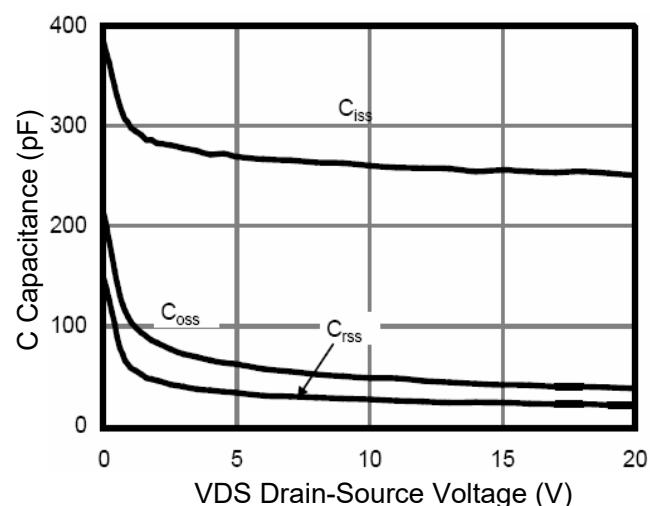


Figure 6 Capacitance vs V_{DS}



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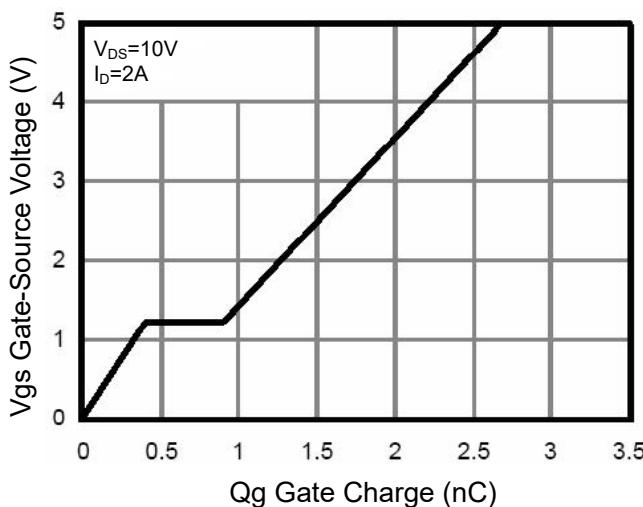


Figure 7 Gate Charge

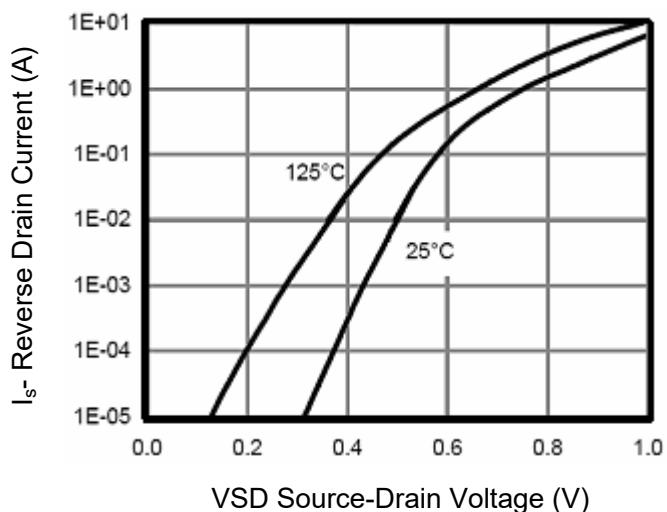


Figure 8 Source-Drain Diode Forward

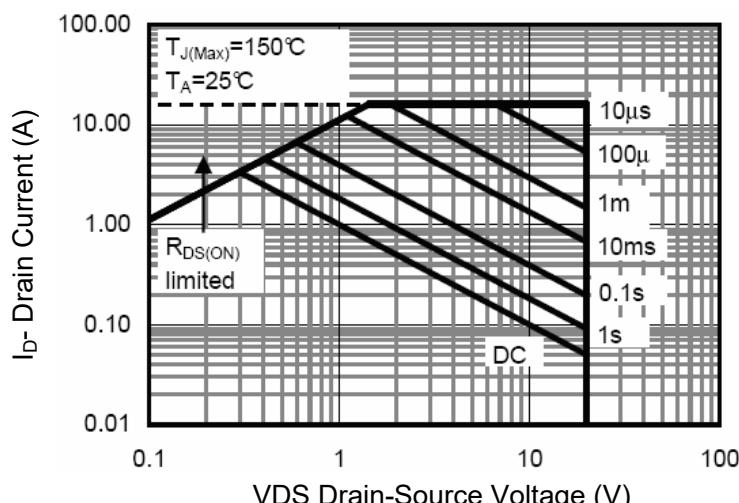


Figure 9 Safe Operation Area

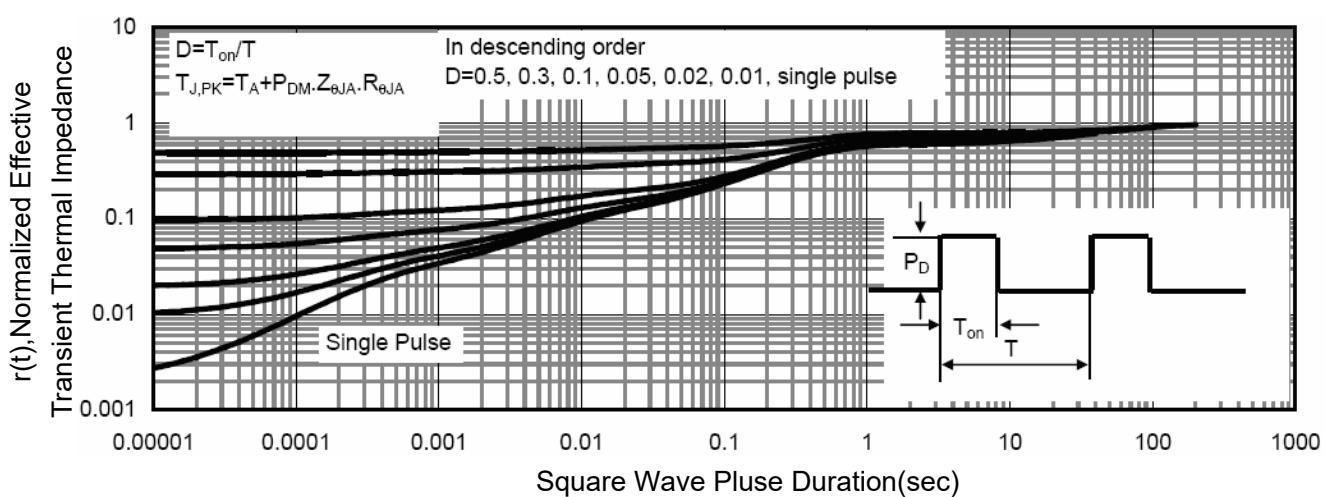
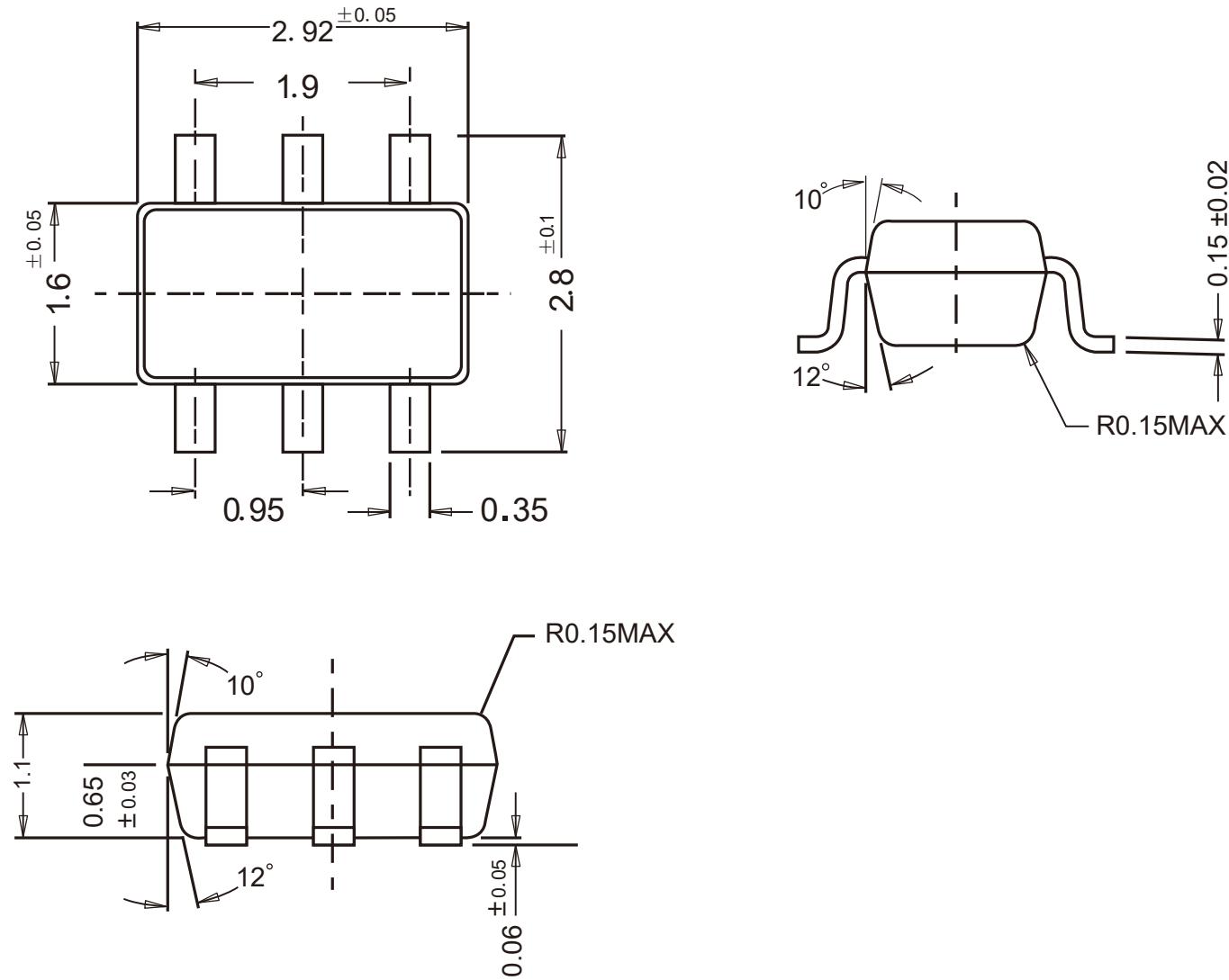


Figure 10 Normalized Maximum Transient Thermal Impedance



Package Outline

SOT-23-6 Dimensions in mm



Ordering Information

Device	Package	Shipping
PJM4602DNSG-S	SOT-23-6	3000/Reel&Tape(7inch)

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